

Micro wave Measurements:-

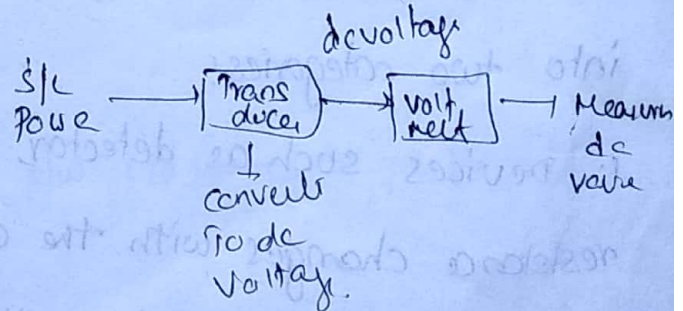
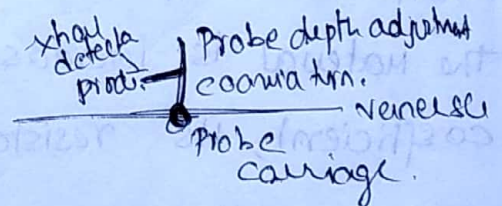
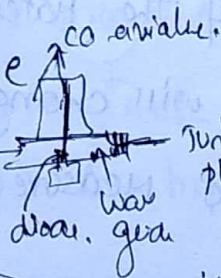
UNIT-5 note is in new note

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1. In low frequency ac ckt containing lumped elements such as voltage, current frequency & power.
2. Impedance, power factor & phase angle can be calculated by using lumped elements.
3. At uwave frequencies the amplitude of voltage & current on a transmission lines are the functions of distance & are not easily measured.
4. In lossless line, The power is independent of the location \therefore it is ~~convenient~~ convenient to measure power instead of voltage & current.
5. At uwave frequencies, Most of the properties of devices and circuits are obtained from the measurement of S-parameters, frequency, phase shift, VSWR, power & noise figure.
6. The vector network analyser, spectrum analyser, power meters are direct uwave measuring instruments. due to high cost in laboratory uwave measurement carried out by a 1 kHz square wave.

Micro wave test equipments:-

1. slotted line carriage
2. Tunable detector
3. power meter
4. spectrum analyser
5. VSWR Meter



Power Measurements:-

- Measurement of microwave power plays an important role in microwave engineering.
- It determines the o/p powers of generators & decides the functioning of transmitting & receiving systems.

$$\therefore P_{av} = I_{rms} \cdot V_{rms} \cdot \cos \phi$$

- But at uwave it is impossible to specify and measure current & voltages because at uwave frequency circuit elements are distributed. This leads to various measurement techniques of uwave power.

→ Depending on power level, there are 3 different methods of measuring uwave power.

1. Measurement of very low power ($< 1 \text{ mW}$);
2. Measurement of low power ($< 10 \text{ mW}$);
3. Measurement of high power (10 mW to 10 W)

Principle:-

When uwave power is absorbed by a material the temperature of the material is increased. If the material has non-zero temperature coefficient, its resistance will change.

→ devices which are used to measure the power will be divided into two categories:

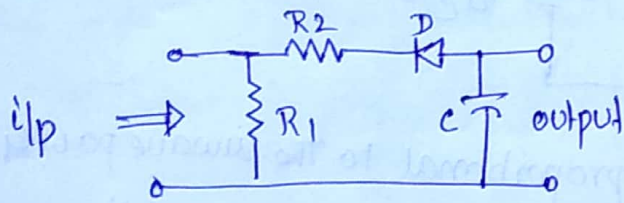
1. Devices such as detector, bolometers & thermocouples → whose resistance changes with the applied power. These devices are used for measuring power in microwatts.
2. calorimeters are not as sensitive but are capable of measuring power as high as hundreds of kilowatts.

[disadvantage:-
1. unstable for small uwave power
2. accuracy = 5%]

→ Most microwave power sources are sensitive to load impedance variations, & must be isolated from them. klystron & magnetrons will subject to output power & frequency variation if the load is mismatched. so, An isolator is thus connected immediately after the power source.

1. Measurement of very low power (<1mw)

2 Methods 1. Schottky barrier diode sensor



R_1, R_2 are biasing resistance, D is a Schottky barrier diode, C : capacitor.

→ If i/p is applied to R_1 , it passes through the resistance R_2 . The diode detects the i/p power & converts the microwave power into heat energy.

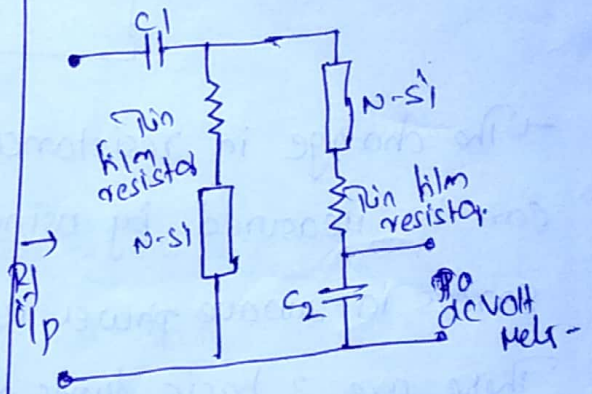
→ The corresponding temp. rise provides a change in electrical parameters. These parameters result in o/p current in low freq. circuit.

2. Measurement of low power (<10mw)

→ for measuring low power typically b/w 1 to 10mw is performed using bolometers.

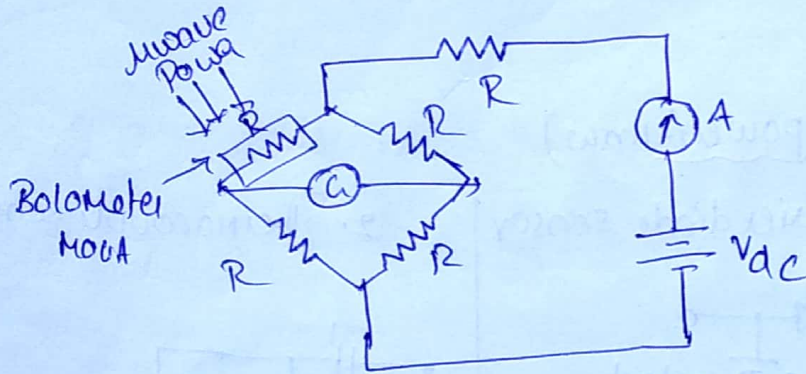
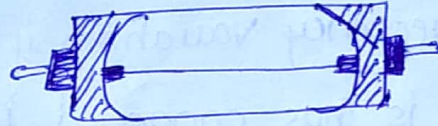
↓
is a most commonly used detecting element in microwave range. Bolometer is a temperature-sensitive element when microwave power falls on it, its temperature rises which results in change

2. Thermocouple sensor.



① Thermocouple is a junction of 2 dissimilar metals or semiconductors.

in resistance. The element with +ive temperature coefficient is used & the element used is bolometer.



→ The change in resistance is proportional to the microwave power which can be measured by using the microwave bridge circuit.

errors in microwave power measurements:-

There are 3 basic types of errors 1. Instrumental error

← 2. substitution error

3. mount inefficiency error.

due to
difference in
heating elements

↓
imperfect matching
of impedance.

↑ instability by biasing source.

Attenuation Measurement:-

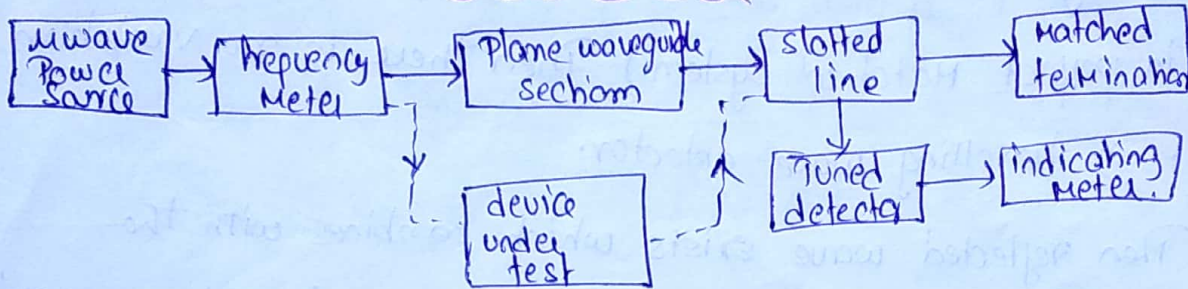
$$\alpha = 10 \log_{10} \left(\frac{P_i}{P_o} \right)$$

P_i : input power to the device
 P_o : output power from the device.

can be performed by 2 methods

1. Direct or power ratio measuring Method
2. RF substitution Method.

1. Power ratio Measurement Method:-

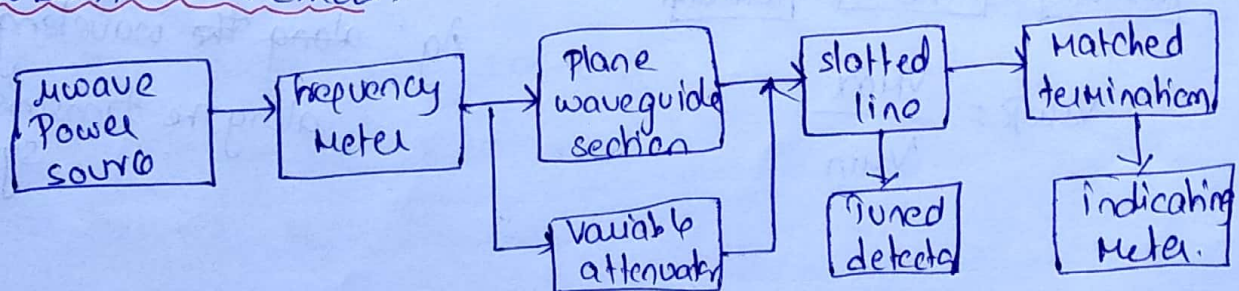


The direct method involves measuring power at two desired points i.e. i/p power & o/p power with and without device of which attenuation is to be measured.

→ It should be measured under matched conditions

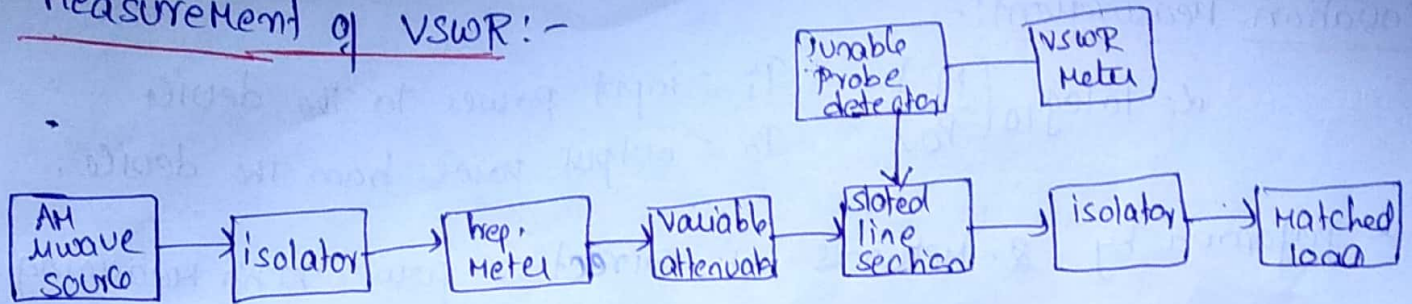
→ Power delivered to the load is measured & then power measured with out load then the ratio of second to the first power gives attenuation.

RF substitution Method:-



→ This method is used when i/p power is low & device has high attenuation.

Measurement of VSWR:-



* VSWR & ^{voltage} reflection coefficient are used for the measurement of load impedance by slotted line.

→ If $Z_0 = Z_L$ (in perfect matched system) Then there is no variation in the output of travelling wave detector.

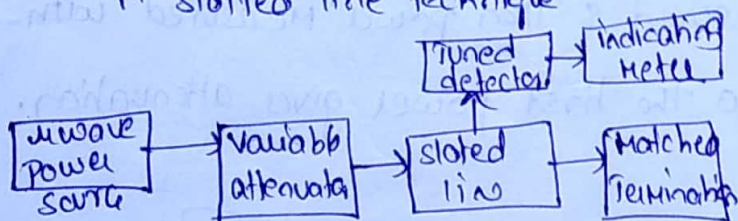
If $Z_0 \neq Z_L$ Then reflected wave exists which combines with the incident wave to create standing wave along the length of the waveguide.

$$V_{SWR} = \frac{V_{max}}{V_{min}}$$

There are two commonly used methods

1. slotted line technique
2. double minimum method.

1. slotted line technique



$$V_{SWR} = \frac{V_{max}}{V_{min}}$$

$$SWR = \frac{\lambda_g}{\lambda(d_2 - d_1)}$$

λ_g : along the wavelength along the transmission system.

Impedance Measurement:-

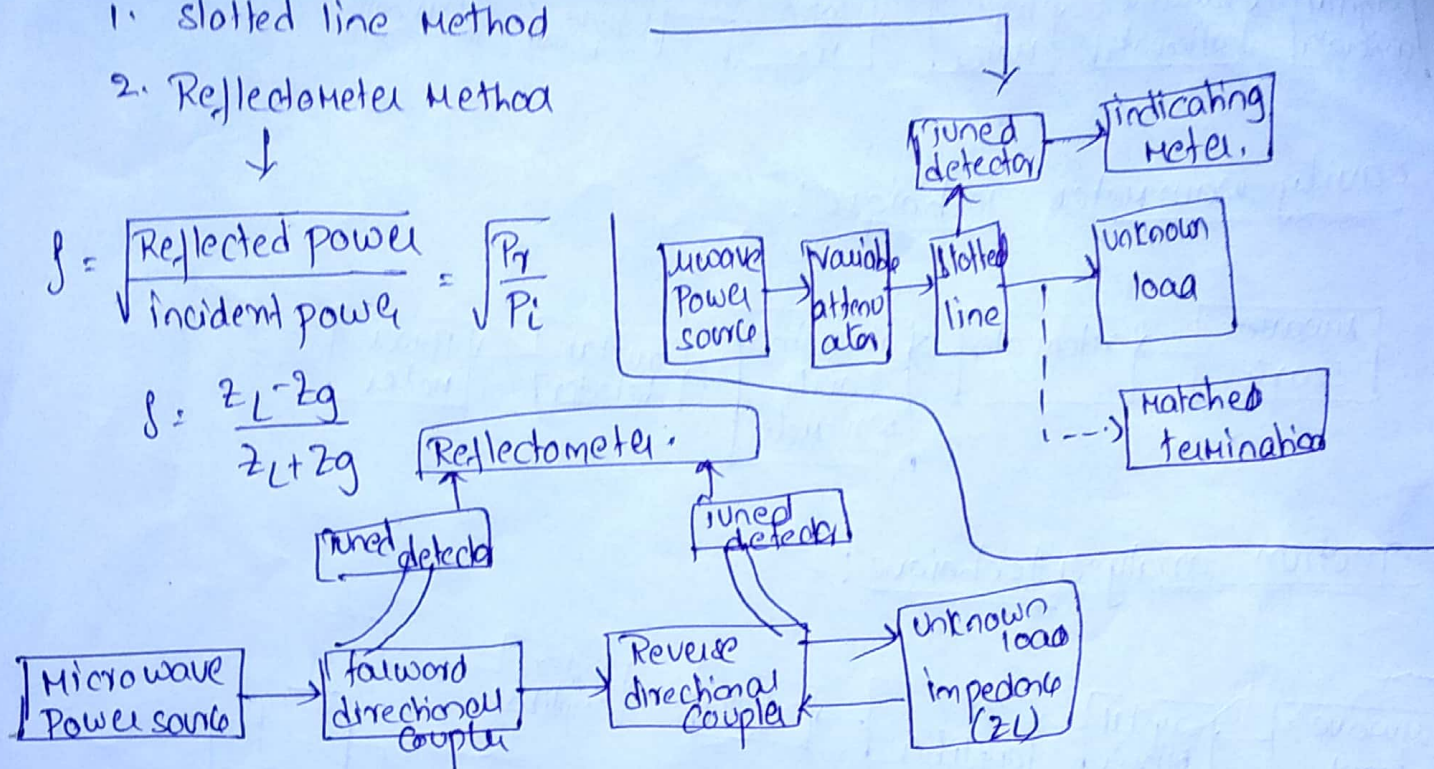
Methods used to measure the impedance at microwave frequency are

1. slotted line method
2. Reflectometer Method



$$\rho = \sqrt{\frac{\text{Reflected power}}{\text{Incident power}}} = \sqrt{\frac{P_r}{P_i}}$$

$$\rho = \frac{Z_L - Z_0}{Z_L + Z_0}$$



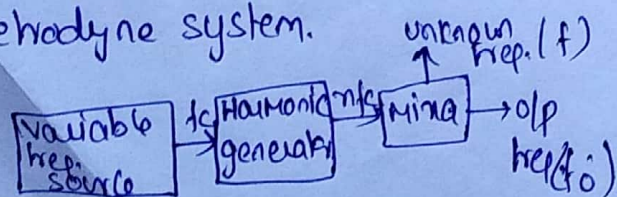
Frequency Measurement:-

There are two techniques to measure microwave frequency

1. Mechanical technique → a) slotted line technique
2. Electronic technique → b) cavity wave meter technique (or) Resonant cavity technique
c) spectrum Analyser method

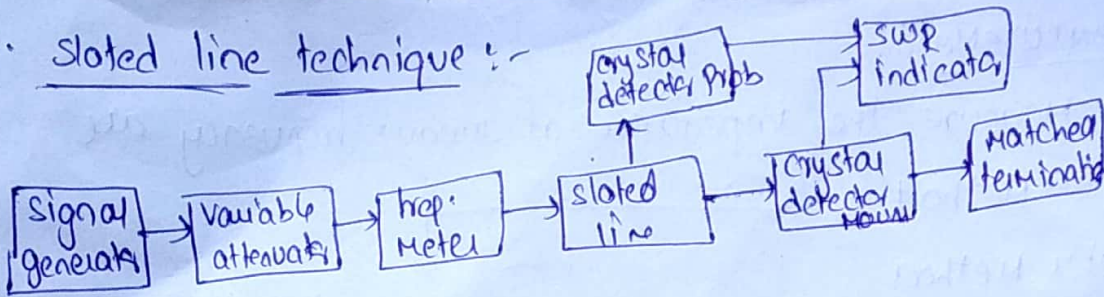


Principle:- electronic technique is based on the comparison of unknown microwave frequency with a harmonic of known frequency by a frequency heterodyne system.

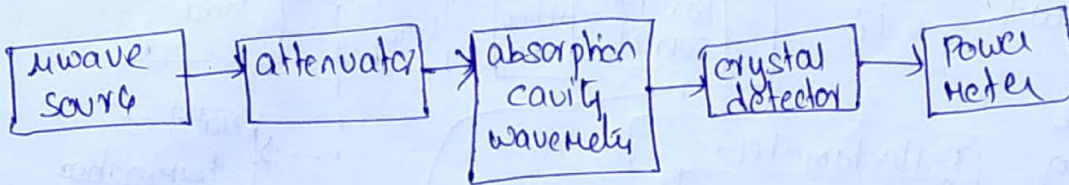


$$f = n f_c - f_o$$

1. Slotted line technique :-



2. cavity wave meter technique :-



3. spectrum analyser technique :-

